

晶体管光耦
Photo Transistor

AT4NXX

Product Data Sheet

AOTE DCC
RELEASE

台湾奥特半导体科技有限公司

TAIWAN AOTE SEMICONDUCTOR TECHNOLOGY CO.,LTD

www.aotesemi.com

概述 Description

AT4NXX是一款由发光二极管和一个光电晶体管组成的光电耦合器。六引脚封装 (DIP6、SMD6)。

The AT4NXX is a photoelectric coupler composed of light-emitting diode and phototransistor. It is packaged in a 6-pin package at DIP、SMD.

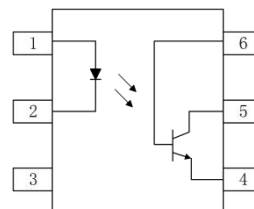
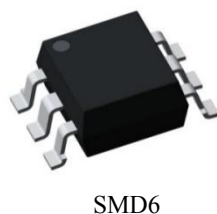
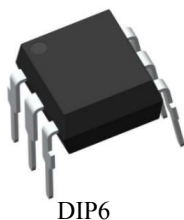
特性 Features

- 电流转换比(CTR)范围: $\geq 20\%$ ($I_F = 10\text{mA}$, $V_{CE} = 10\text{V}$, $T_a = 25^\circ\text{C}$) Current transfer ratio: $\geq 20\%$ ($I_F = 10\text{mA}$, $V_{CE} = 10\text{V}$, $T_a = 25^\circ\text{C}$)
- 输入-输出隔离电压 ($V_{ISO} = 5000\text{ Vrms}$)
High isolation voltage between input and output($V_{ISO} = 5000\text{ Vrms}$)
- 输入-输出隔离电阻 (典型值 $R_{iso} = 10^{11}\Omega$)
Input-output isolation voltage resistance ($R_{iso} = 10^{11}\Omega$)
- 工作温度: $-55^\circ\text{C} \sim 100^\circ\text{C}$
Operating Temperature: $-55^\circ\text{C} \sim 100^\circ\text{C}$
- 符合加强绝缘标准
Meet reinforced insulation standards
- 符合安规标准: UL 1577, VDE DIN EN60747-5-5 (VDE 0884-5), CQC11-471543-2022
Meet safety standard approval: UL 1577, VDE DIN EN60747-5-5 (VDE 0884-5), CQC11-471543-2022

应用 Applications

- 电源调节器
Power regulator
- 数字逻辑输入
Digital logic input
- 微处理器输入
Microprocessor input

封装和原理图 Package and Schematic Diagram



Pin Configuration

1. Anode
2. Cathode
3. NC
4. Emitter
5. Collector
6. Base



产品型号命名规则 Order Code

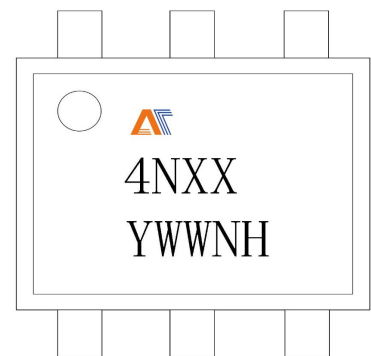
AT 4NXX - UN Y - W (V) (ZZ)

① ② ③ ④ ⑤ ⑥ ⑦

- ① 公司代码 Company Code (AT: 奥特AOTE)
- ② 产品系列 Product Series (XX: 25, 26, 27,28,35,36,37,38)
- ③ 框架类型 Lead Frame (Cu: 铜框架 Copper)
- ④ 树脂类型 Epoxy (H: 无卤 Halogen-free)
- ⑤ 封装形式 Package (D: DIP ; S: SMD)
- ⑥ 器件工作温度范围 Device Operating Temperature Range (特殊范围需填或者空白 Special Range or None)
- ⑦ 内部补充代码 Internal Supplementary Code (数字或者空白 Number or None)

印字信息 Marking Information

- 印字中 “” 为奥特品牌 LOGO
 “” denotes LOGO
- 印字中的 “XX” 代表产品分档 : 25, 26, 27,28,35,36,37,38
 “XX” denotes the classification : 25, 26, 27,28,35,36,37,38
- 印字中 “Y” 代表年份 ; A(2018),B(2019),C(2020).....
 “Y” denotes YEAR : A(2018), B(2019), C(2020).....
- 印字中 “WW” 代表周号
 “WW” denotes Week’ s number
- 印字中 “E” 代表产品版本号
 “E” denotes product versions
- 印字中的 “H” 代表无卤
 “H” denotes Halogen-free



绝缘和安规信息 Insulation and Safety related specifications

项目 Item	符号 Symbol	数值 Value	单位 Unit	备注 Remark
爬电距离 Creepage Distance	L	>7.0	mm	从输入端到输出端，沿本体最短距离路径 Measured from input terminals to output terminals, shortest distance path along body
电气间隙 Clearance Distance	L	>7.0	mm	从输入端到输出端，通过空气的最短距离 Measured from input terminals to output terminals, shortest distance through air
绝缘距离 Insulation Thickness	DTI	> 0.4	mm	发射器和探测器之间的绝缘厚度 Insulation thickness between emitter and detector
峰值隔离电压 Peak Isolation Voltage	V_{IORM}	1500	V_{peak}	DIN/EN/IEC EN60747-5-5
瞬态隔离电压 Transient isolation voltage	V_{IOTM}	7000	V_{peak}	DIN/EN/IEC EN60747-5-5
隔离电压 Isolation Voltage	Viso	>5000	V_{rms}	For 1 min, RH < 60%

极限参数 Absolute Maximum Ratings (Ta = 25°C)

参数 Parameter		符号 Symbol	额定值 Rating	单位 Unit
发射端 Input	正向电流 Forward Current	I_F	60	mA
	峰值正向电流(1us, 脉冲) Peak forward current (1us, pulse)	I_{FP}	1000	mA
	反向电压 Reverse Voltage	V_R	6	V
	功耗 Power Dissipation	P_D	100	mW
接收端 output	集电极功耗 Collector Power Dissipation	P_C	300	mW
	集电极电流 Collector Current	I_C	100	mA
	集电极-基极电压 Collector-Base Voltage	V_{CBO}	70	V
	集电极-发射极电压 Collector-Emitter Voltage	V_{CEO}	30	V
	发射极-集电极电压 Emitter - Collector Voltage	V_{ECO}	7	V
总功耗 Total Power Dissipation	P_{tot}	350	mW	
输入输出瞬态耐受电压 Input-output isolation voltage	Viso	5000	V_{rms}	
工作温度 Operating Temperature	T_{opr}	-55 ~ +100	°C	
存储温度 Storage Temperature	T_{stg}	-55 ~ +125	°C	
焊接温度 Soldering Temperature	T_{sol}	260	°C	

产品特性参数 Electro-optical Characteristics (Ta = 25°C)

参数 Parameter		符号 Symbol	条件 Condition	最小 Min.	典型 Typ.	最大 Max.	单位 Unit	
发射端 Input	正向电压 Forward Voltage	V_F	$I_F = 10\text{mA}$	-	1.2	1.5	V	
	反向电流 Reverse Current	I_R	$V_R = 3\text{V}$	-	-	10	μA	
	输入电容 Terminal Capacitance	C_t	$V=0, F=1\text{KHz}$	-	50	-	pF	
接收端 Output	集电极暗电流 Collector Dark Current	I_{CEO}	$V_{CE} = 10\text{V}$	-	-	50	nA	
	集电极-基极击穿电压 Collector-Base Breakdown Voltage	BV_{CBO}	$I_b = 0.1\text{mA}, I_f = 0$	70	-	-	V	
	集电极-发射极击穿电压 Collector-Emitter Breakdown Voltage	BV_{CEO}	$I_c = 0.1\text{mA}, I_f = 0$	30	-	-	V	
	发射极-集电极击穿电压 Emitter-Collector Breakdown Voltage	BV_{ECO}	$I_e = 0.01\text{mA}, I_f = 0$	7	-	-	V	
传输特性 Transfer Characteristics	电流传输比 Current Transfer Ratio	4N25、4N26、4N38	CTR^*	$I_F = 10\text{mA}, V_{CE} = 10\text{V}$	20	-	-	%
		4N27、4N28			10	-	-	%
		4N35、4N36、4N37			100	-	-	%
	集电极-发射极饱和压降 Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_F = 50\text{mA}, I_C = 2\text{mA}$	-	-	0.3	V	
	隔离电阻 Isolation Resistance	R_{ISO}	DC=500V 40~60%R.H.	5×10^{10}	1×10^{11}	-	Ω	
	隔离电容 Isolation capacitance	C_{ISO}	$V=0, F=1\text{MHz}$	-	1	2.5	pF	
	上升时间 Rise Time	T_r	$V_{CE} = 10\text{V}, I_C = 2\text{mA}, R_L = 100\Omega$	-	4	-	μs	
下降时间 Fall Time	T_f	-		3	-	μs		

 注*：电流传输比= $I_C/I_F \times 100\%$ 。

 Note*： $CTR = I_C/I_F \times 100\%$ 。

典型光电特性曲线 Typical Electro-Optical Characteristics Curves

Fig.1 Relative Current Transfer Ratio vs. Forward Current

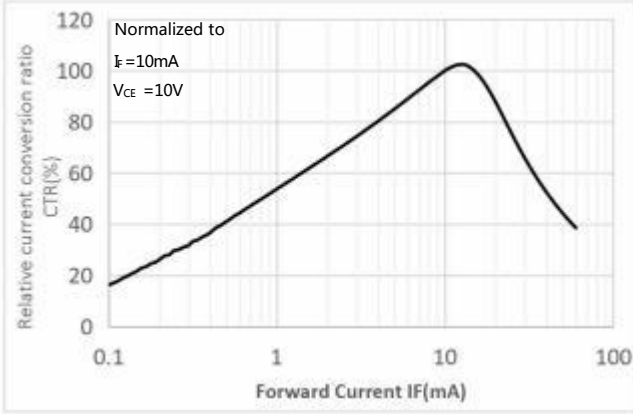


Fig.2 Forward Current vs. Forward Voltage

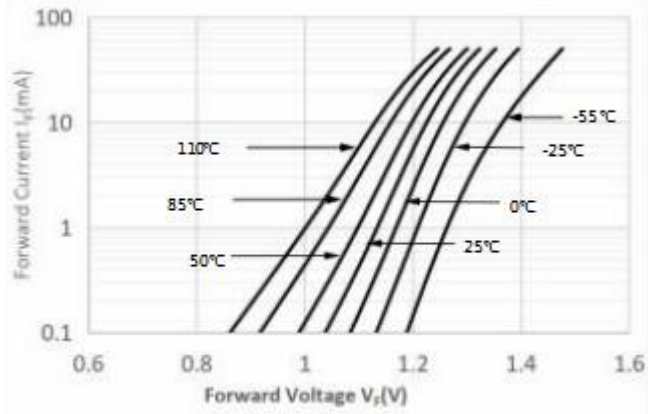


Fig.3 Collector Current vs. Collector-emitter Voltage

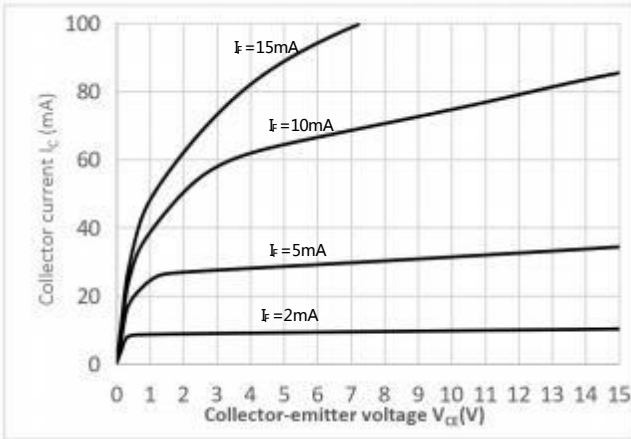


Fig.4 Relative Current Transfer Ratio vs. Ambient Temperature

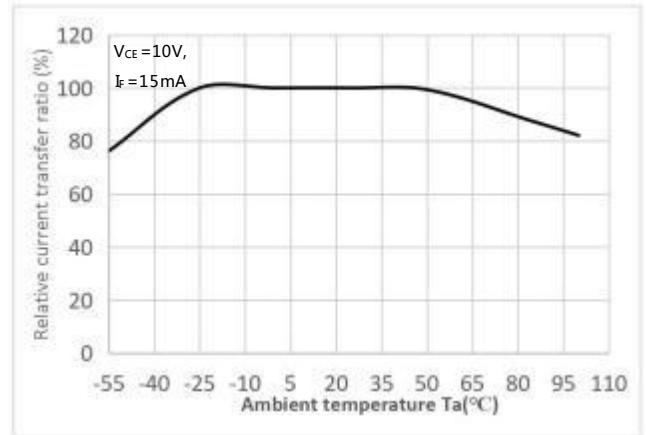


Fig.5 Collector Dark Current vs Ambient Temperature

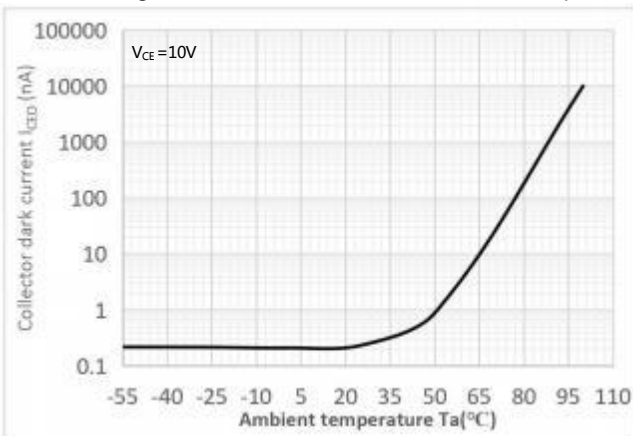


Fig.6 Response Time vs. Load Resistance

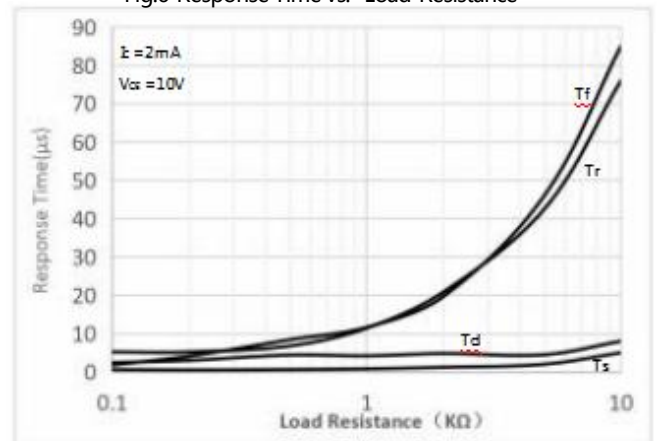


Fig.7 Frequency Response

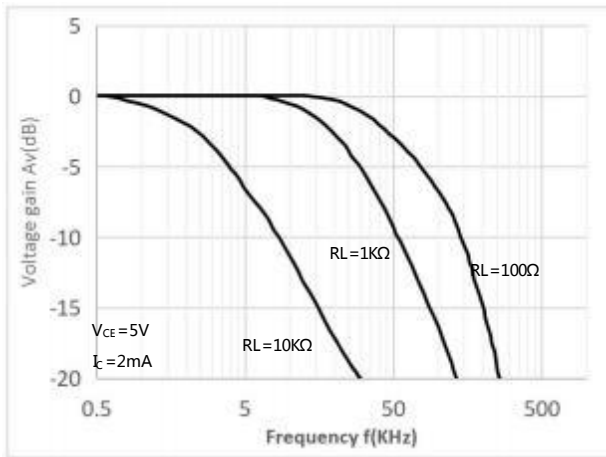


Fig.8 Collector-emitter Saturation Voltage vs Forward Current

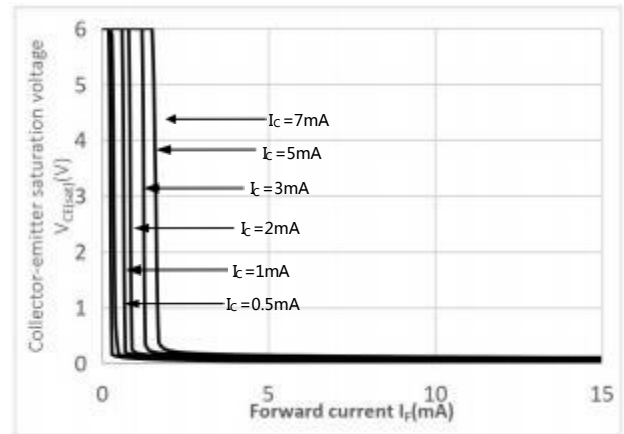
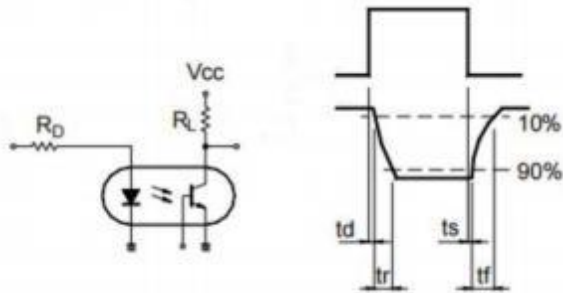
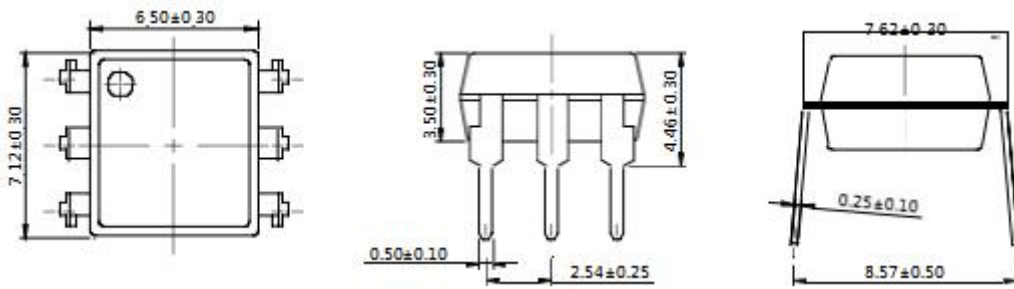


Fig.9 Switching Time Test Circuit & Waveforms

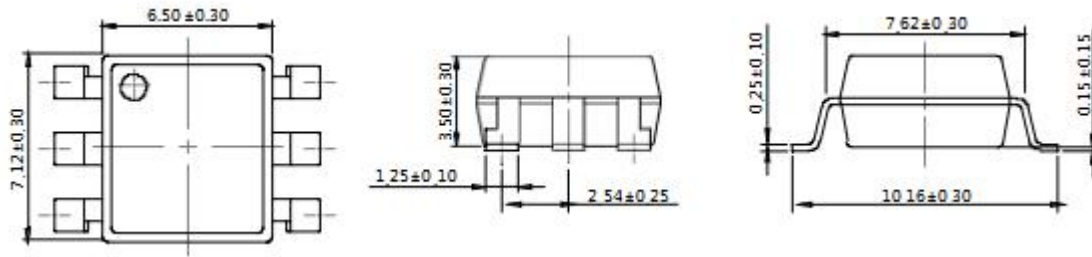


外形尺寸 Outline Dimensions

DIP6



SMD6



单位 Unit: mm

回流焊温度曲线图 Solder Reflow Profile



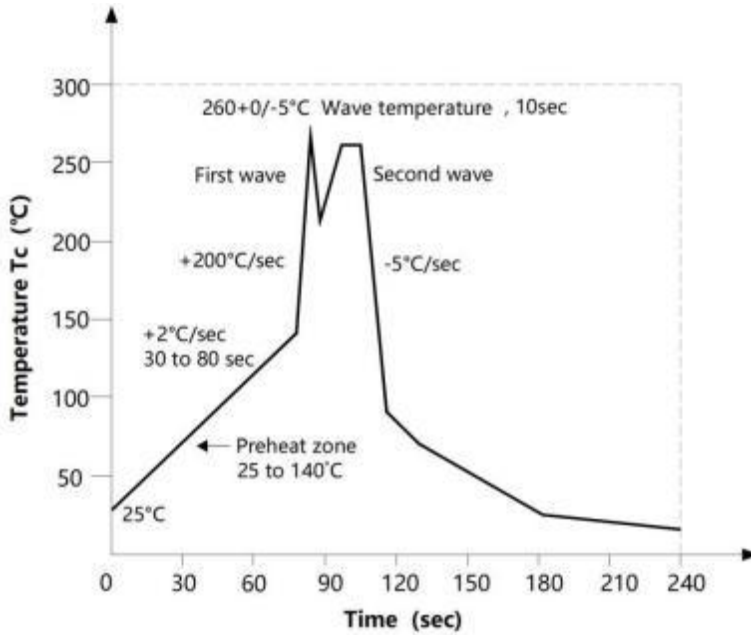
项目 Item	符号 Symbol	最小值 Min.	最大值 Max.	单位 Unit
预热温度 Preheat Temperature	T_s	150	200	$^\circ\text{C}$
预热时间 Preheat Time	t_s	60	120	s
升温速率 Ramp-Up Rate (T_L to T_P)	-	-	3	$^\circ\text{C/s}$
液相线温度 Liquidus Temperature	T_L	217		$^\circ\text{C}$
时间高于 T_L Time Above T_L	t_L	60	150	s
峰值温度 Peak Temperature	T_P	-	260	$^\circ\text{C}$
T_c 在 $(T_P - 5)$ 和 T_P 之间的时间 Time During Which T_c Is Between $(T_P - 5)$ and T_P	t_p	-	30	s
降温速率 Ramp-down Rate (T_P to T_L)	-	-	6	$^\circ\text{C/s}$

注 Note :

建议在所示的温度和时间条件下进行回流焊，最多不能超过三次；

Reflow soldering is recommended at the temperatures and times shown, no more than three times;

波峰焊温度曲线图 Wave Soldering Profile



手工烙铁焊接 Soldering with hand soldering iron

- A. 手工烙铁焊仅用于产品返修或样品测试；
Hand soldering iron is only used for product rework or sample testing;
- B. 手工烙铁焊要求：温度 $360^{\circ}\text{C} \pm 5^{\circ}\text{C}$ ，时间 $\leq 3\text{s}$ 。
Manual soldering method Temperature: $360^{\circ}\text{C} \pm 5^{\circ}\text{C}$, within 3s.

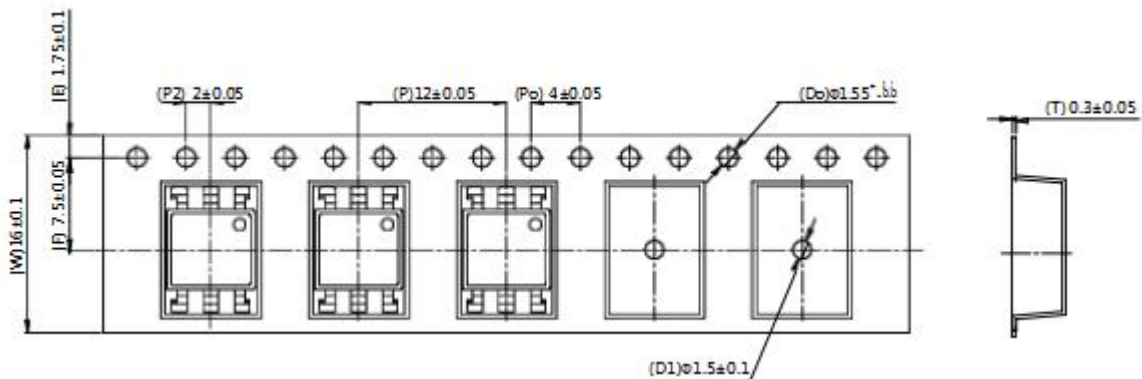
包装 Packing

■ 汇总表 Summary table

封装形式	包装方式	盘数量	盒数量	箱数量	静电袋规格	盒规格	箱(双瓦楞)规格	备注
Package Type	Packing Form	Quantity per Reel	Quantity per Box	Quantity per Carton	Antistatic Bag Specification	Box Specification	Carton Specification	Note
SMD6	卷盘 ($\phi 330\text{mm}$ 蓝盘)	1000 只/盘	2 盘/盒	10 盒/箱	450*390*0.1mm	340*60*340mm	620*360*365mm	首尾端空至少 200mm
DIP6	管装 (500*12*11mm)	65 只/管	50 管/盒	10 盒/箱	不适用	525*128*56mm	535*275*300mm	每管使用蓝白胶塞, 方向须一致
SMD6	Reel ($\phi 330\text{mm}$ Blue)	1000 pcs/reel	2 reels/box	10 boxes/ctn	450*390*0.1mm	340*60*340mm	620*360*365mm	Guard band 200mm min.
DIP6	Tube (500*12*11mm)	65 pcs/tube	50 tubes/box	10 boxes/ctn	NA	525*128*56mm	535*275*300mm	Endplug (blue) and Endplug (white) keep the direction

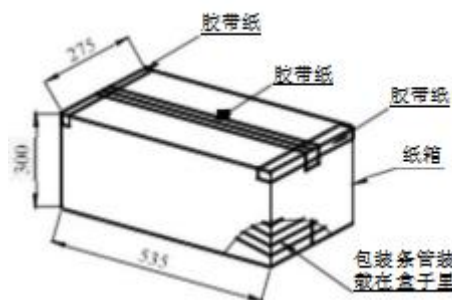
■ 编带包装 Tape & Reel

- 1) 每卷数量：1000 只。
Qty/reel : 1000 pcs.
- 2) 每箱数量：20000 只。
Qty/ctn : 20000 pcs.
- 3) 内包装：每盒 2 盘。
Inner packing : 2 reels/box.
- 4) 示意图 Schematic :



■ 管条包装 Tape & Tube

- 1) 每管数量：65 只。
Qty/Tube : 65 pcs.
- 2) 每箱数量：32500 只。
Qty/ctn : 32500 pcs.
- 3) 内包装：每盒 50 管。
Inner packing : 50 Tube/box.
- 4) 示意图 Schematic



单位/Unit : mm

注意 Attention

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